NSN 5961-01-332-8086

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-332-8086 **Inclosure Material:** Metal **Overall Length:** Between 1.829 inches and 2.578 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-114 **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 1.031 inches and 1.065 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 100.00 amperes source cutoff current **Power Rating Per Characteristic:** 350.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 15.0 static forward current transfer ratio, common-emitter and 60.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 wire hook Shelf Life: N/a **Unit Of Measure:**

No

Fiig:

A110a0

Demilitarization: